

Triple 300MHz Current Feedback Amplifier with Enable



The EL5393A is a triple current feedback amplifier with a bandwidth of 300MHz. This makes these amplifiers ideal for today's high speed video and monitor applications.

With a supply current of just 4mA per amplifier and the ability to run from a single supply voltage from 5V to 10V, these amplifiers are also ideal for hand held, portable or battery powered equipment.

The EL5393A also incorporates an enable and disable function to reduce the supply current to 100µA typical per amplifier. Allowing the CE pin to float or applying a low logic level will enable the amplifier.

For applications where board space is critical, the EL5393A is offered in 16-pin QSOP package, as well as an industry standard 16-pin SO (0.150"). The EL5393A operates over the industrial temperature range of -40°C to +85°C.

Ordering Information

PART NUMBER	PART MARKING	PACKAGE	PKG. DWG. #
EL5393ACS	EL5393ACS	16-Pin SO (0.150")	MDP0027
EL5393ACS-T7*	EL5393ACS	16-Pin SO (0.150") Tape and Reel	MDP0027
EL5393ACS-T13*	EL5393ACS	16-Pin SO (0.150") Tape and Reel	MDP0027
EL5393ACU	5393ACU	16-Pin QSOP	MDP0040
EL5393ACU-T7*	5393ACU	16-Pin QSOP Tape and Reel	MDP0040
EL5393ACU-T13*	5393ACU	16-Pin QSOP Tape and Reel	MDP0040

*Please refer to TB347 for details on reel specifications.

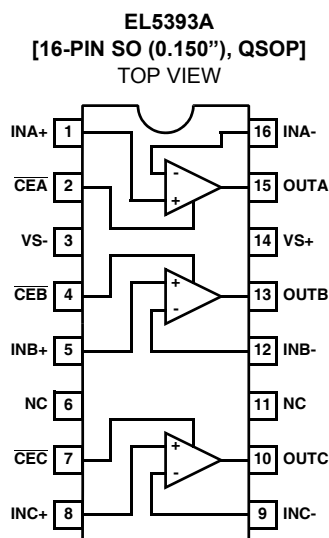
Features

- 300MHz -3dB bandwidth
- 4mA supply current (per amplifier)
- Single and dual supply operation, from 5V to 10V
- Fast enable/disable
- Available in 16-pin QSOP package
- Single (EL5193) and dual (EL5293) available
- High speed, 1GHz product available (EL5191)
- High speed, 6mA, 600MHz product available (EL5192, EL5292, and EL5392)

Applications

- Battery-powered equipment
- Hand-held, portable devices
- Video amplifiers
- Cable drivers
- RGB amplifiers
- Test equipment
- Instrumentation
- Current to voltage converters

Pinout



Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

Supply Voltage between V_{S+} and V_{S-} 11V
 Pin Voltages $V_{S-} -0.5\text{V}$ to $V_{S+} +0.5\text{V}$
 Maximum Continuous Output Current 50mA

Thermal Information

Power Dissipation See Curves
 Storage Temperature -65°C to $+150^\circ\text{C}$
 Ambient Operating Temperature -40°C to $+85^\circ\text{C}$
 Operating Junction Temperature 125°C

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Specifications $V_{S+} = +5\text{V}$, $V_{S-} = -5\text{V}$, $R_F = 750\Omega$ for $A_V = 1$, $R_F = 375\Omega$ for $A_V = 2$, $R_L = 150\Omega$, $T_A = 25^\circ\text{C}$ unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
AC PERFORMANCE						
BW	-3dB Bandwidth	$A_V = +1$		300		MHz
		$A_V = +2$		200		MHz
BW1	0.1dB Bandwidth			20		MHz
SR	Slew Rate	$V_O = -2.5\text{V}$ to $+2.5\text{V}$, $A_V = +2$	1900	2200		V/ μs
t_S	0.1% Settling Time	$V_{OUT} = -2.5\text{V}$ to $+2.5\text{V}$, $A_V = -1$		12		ns
C_S	Channel Separation	$f = 5\text{MHz}$		60		dB
e_N	Input Voltage Noise			4.4		nV/ $\sqrt{\text{Hz}}$
i_{N-}	IN- Input Current Noise			17		pA/ $\sqrt{\text{Hz}}$
i_{N+}	IN+ Input Current Noise			50		pA/ $\sqrt{\text{Hz}}$
dG	Differential Gain Error (Note 1)	$A_V = +2$		0.03		%
dP	Differential Phase Error (Note 1)	$A_V = +2$		0.04		°
DC PERFORMANCE						
V_{OS}	Offset Voltage		-10	1	10	mV
$T_C V_{OS}$	Input Offset Voltage Temperature Coefficient	Measured from T_{MIN} to T_{MAX}		5		$\mu\text{V}/^\circ\text{C}$
R_{OL}	Transimpedance		300	600		k Ω
INPUT CHARACTERISTICS						
CMIR	Common Mode Input Range		± 3	± 3.3		V
CMRR	Common Mode Rejection Ratio		42	50		dB
$+I_{IN}$	+ Input Current		-60	1	80	μA
$-I_{IN}$	- Input Current		-35	1	35	μA
R_{IN}	Input Resistance			45		k Ω
C_{IN}	Input Capacitance			0.5		pF
OUTPUT CHARACTERISTICS						
V_O	Output Voltage Swing	$R_L = 150\Omega$ to GND	± 3.4	± 3.7		V
		$R_L = 1\text{k}\Omega$ to GND	± 3.8	± 4.0		V
I_{OUT}	Output Current	$R_L = 10\Omega$ to GND	95	120		mA
SUPPLY						
I_{SON}	Supply Current - Enabled	No load, $V_{IN} = 0\text{V}$	3	4	5	mA
I_{SOFF}	Supply Current - Disabled	No load, $V_{IN} = 0\text{V}$		300	450	μA

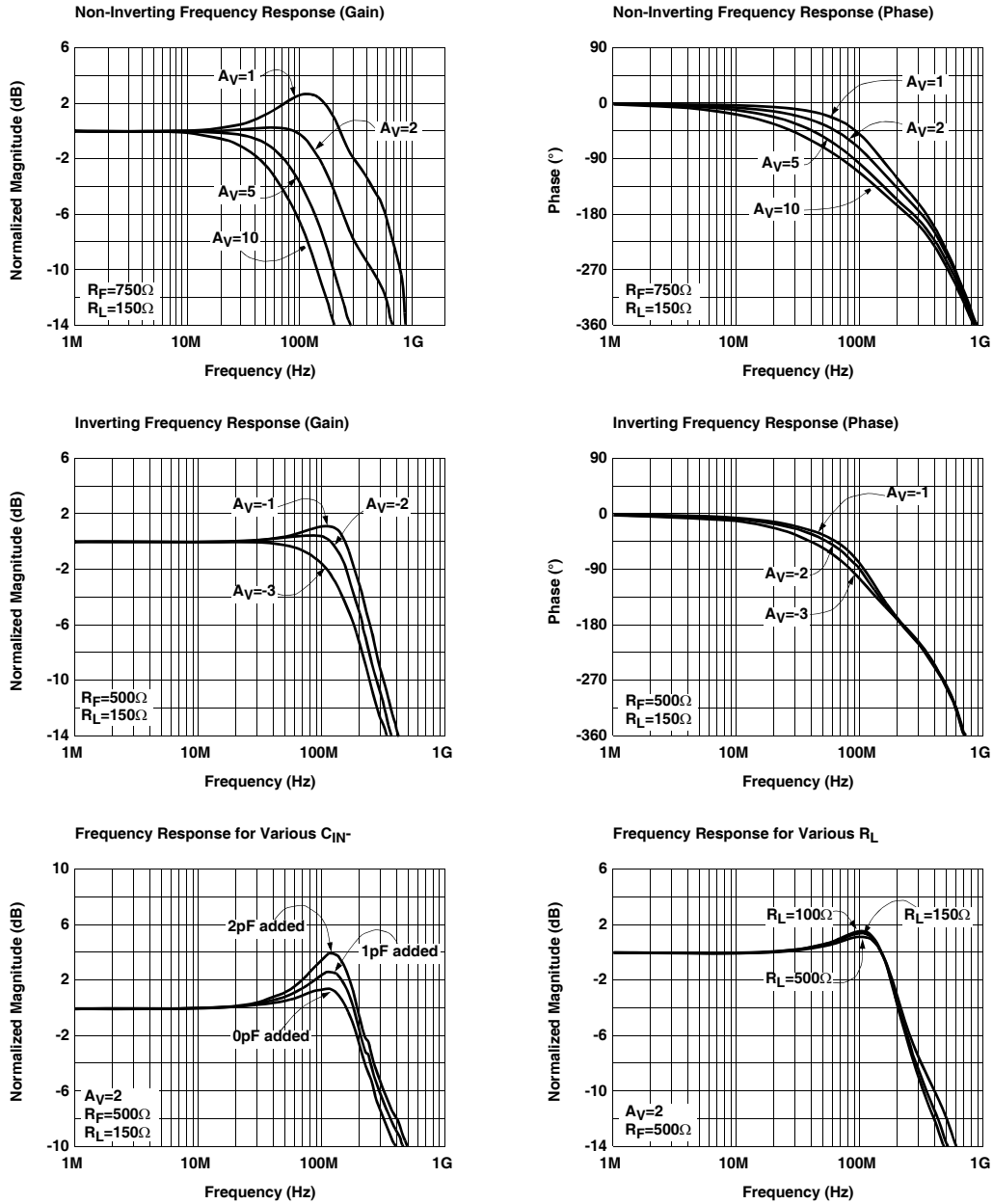
Electrical Specifications $V_{S+} = +5V$, $V_{S-} = -5V$, $R_F = 750\Omega$ for $A_V = 1$, $R_F = 375\Omega$ for $A_V = 2$, $R_L = 150\Omega$, $T_A = 25^\circ C$ unless otherwise specified. **(Continued)**

PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
PSRR	Power Supply Rejection Ratio	DC, $V_S = \pm 4.75V$ to $\pm 5.25V$	55	75		dB
-IPSR	- Input Current Power Supply Rejection	DC, $V_S = \pm 4.75V$ to $\pm 5.25V$	-2		2	$\mu A/V$
ENABLE						
t_{EN}	Enable Time			40		ns
t_{DIS}	Disable Time			600		ns
I_{IHCE}	CE Pin Input High Current	$\overline{CE} = V_{S+}$		0.8	6	μA
I_{ILCE}	CE Pin Input Low Current	$\overline{CE} = V_{S-}$		0	-0.1	μA
V_{IHCE}	CE Input High Voltage for Power-down		$V_{S+} - 1$			V
V_{ILCE}	CE Input Low Voltage for Power-down				$V_{S+} - 3$	V

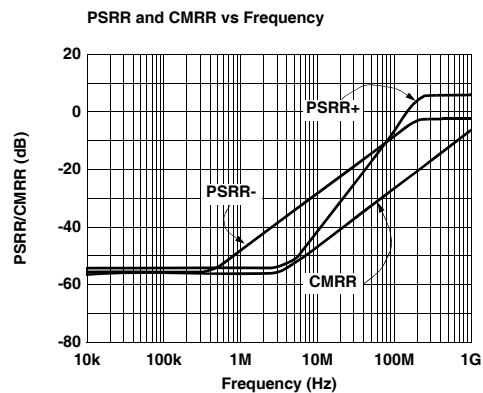
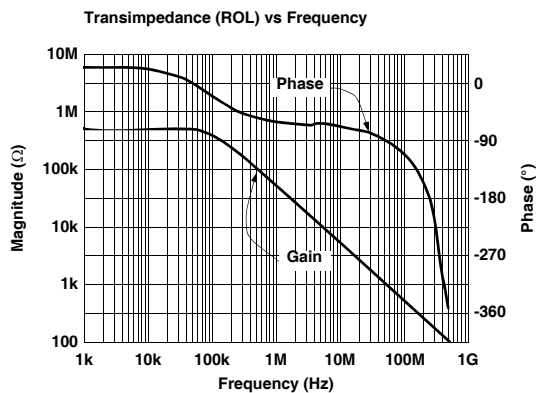
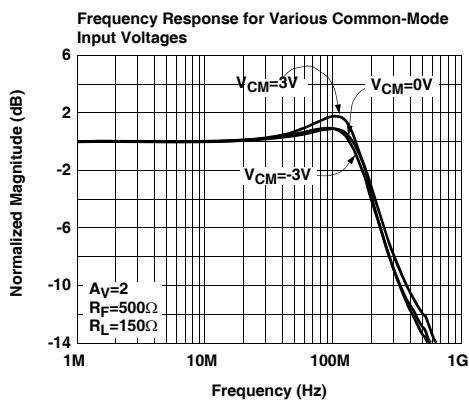
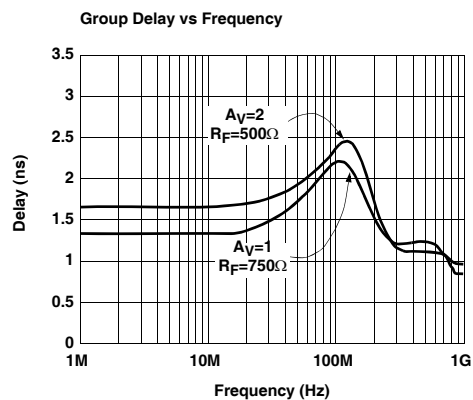
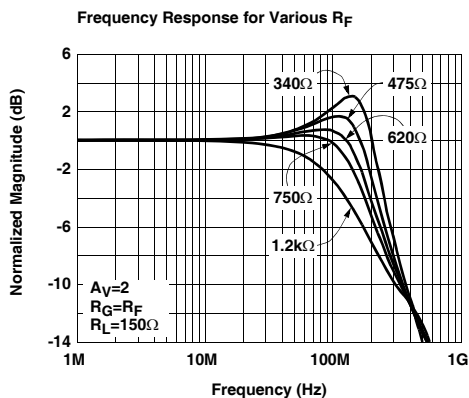
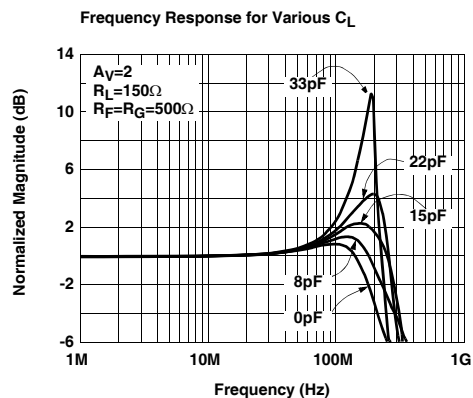
NOTE:

1. Standard NTSC test, AC signal amplitude = $286mV_{P-P}$, $f = 3.58MHz$.

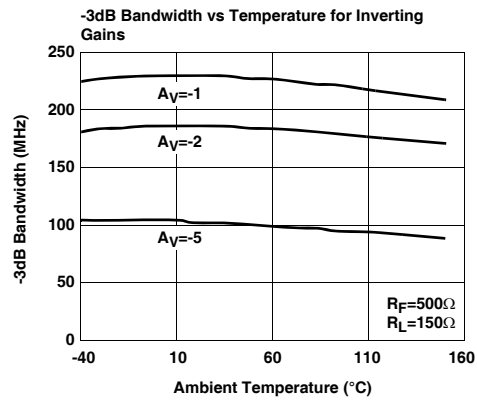
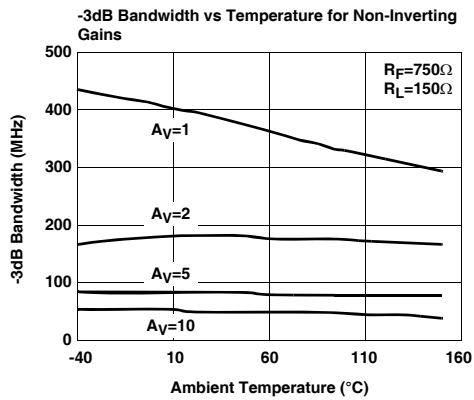
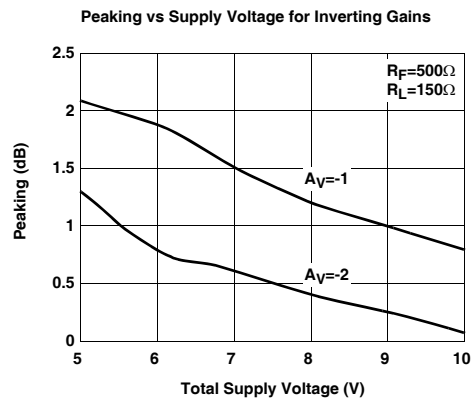
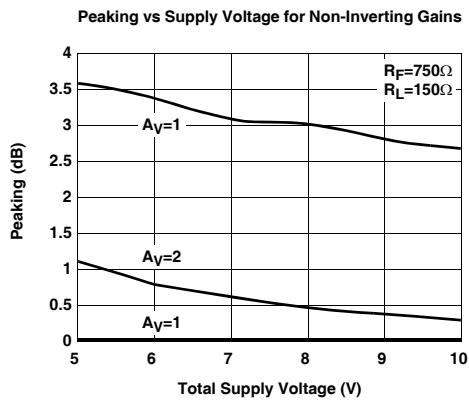
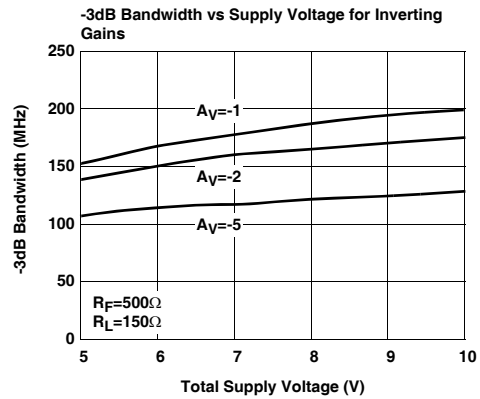
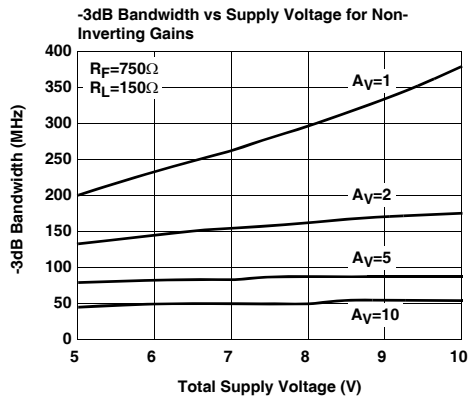
Typical Performance Curves



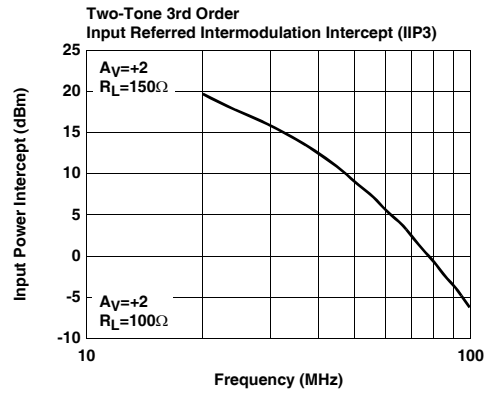
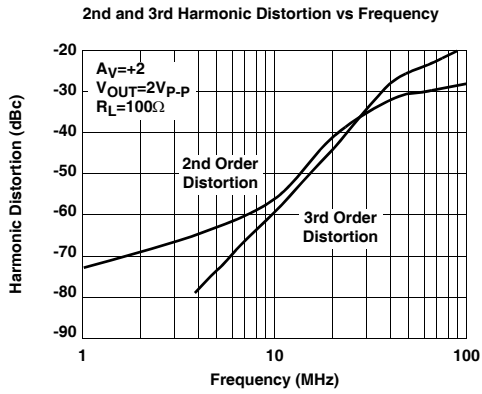
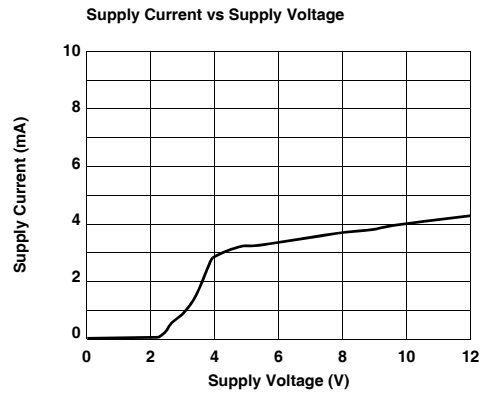
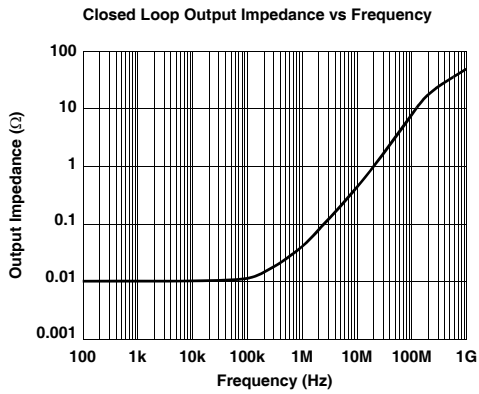
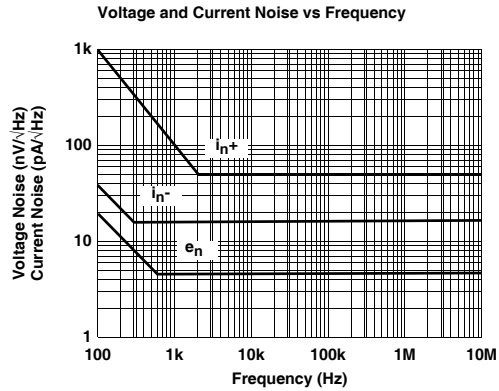
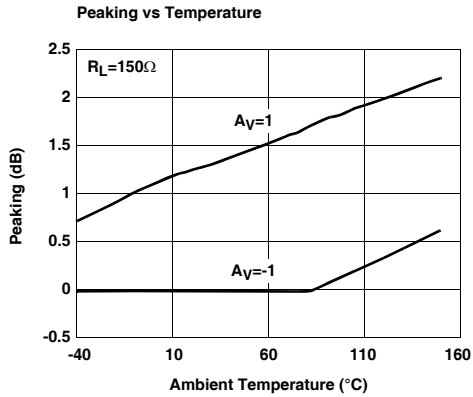
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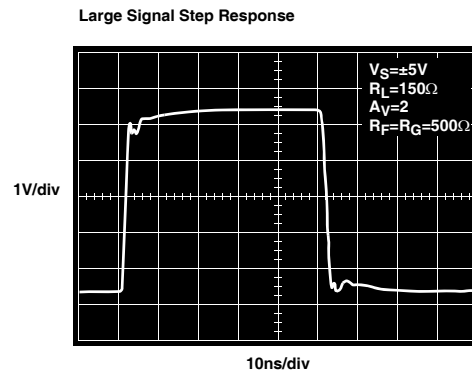
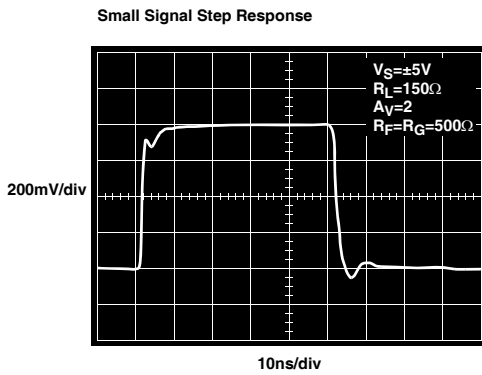
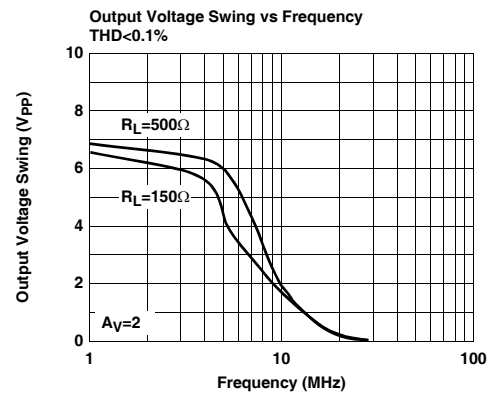
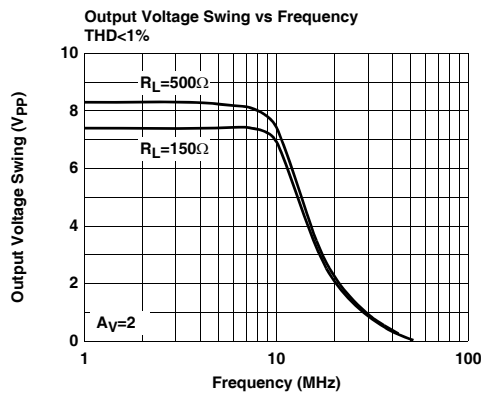
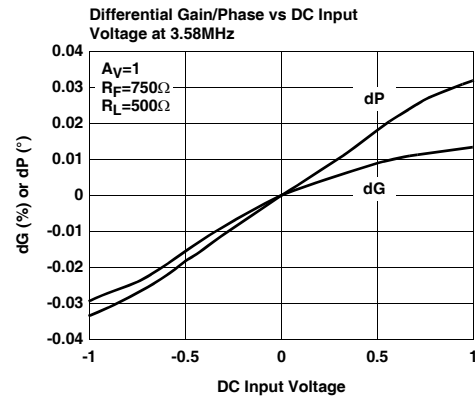
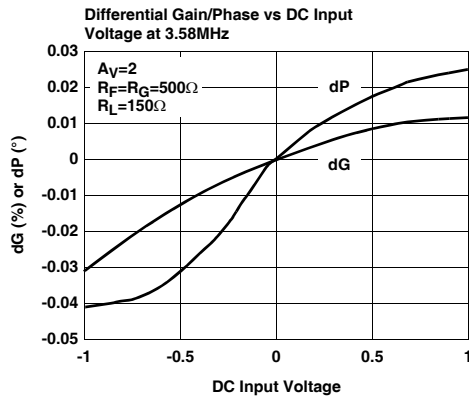
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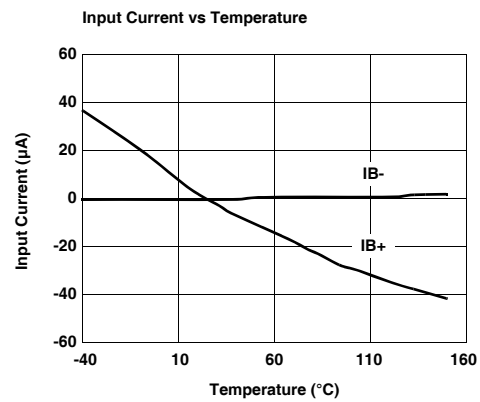
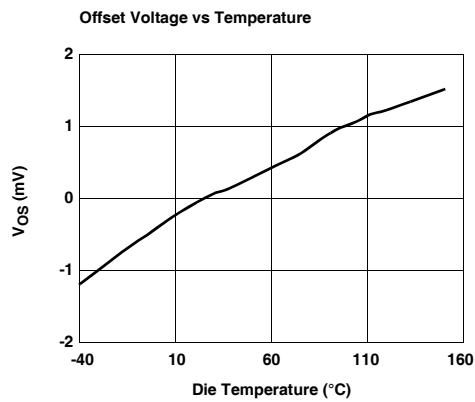
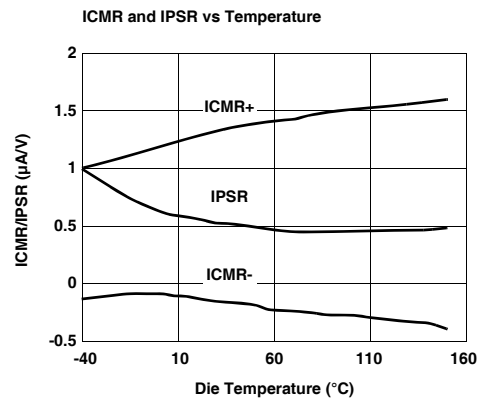
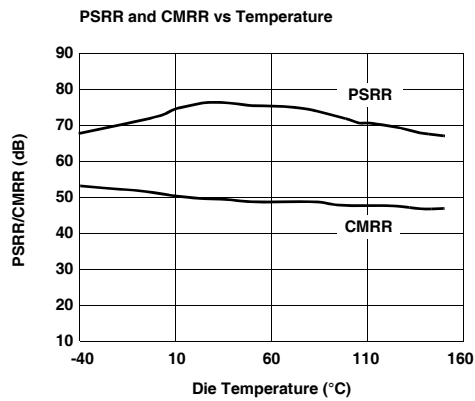
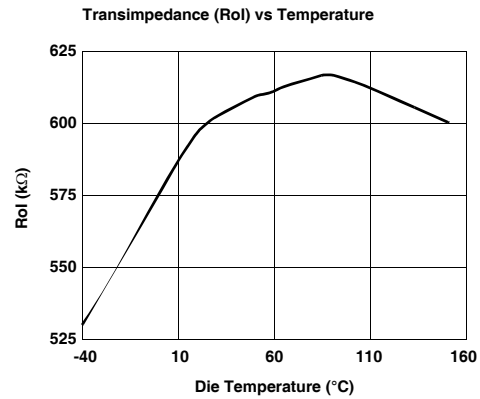
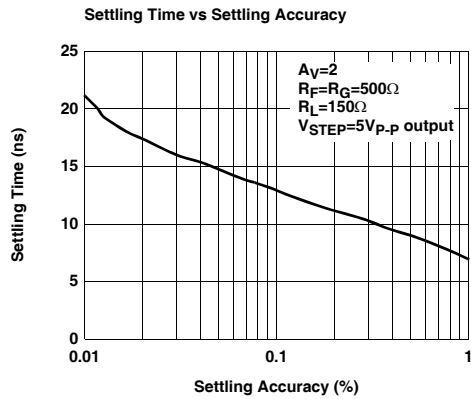
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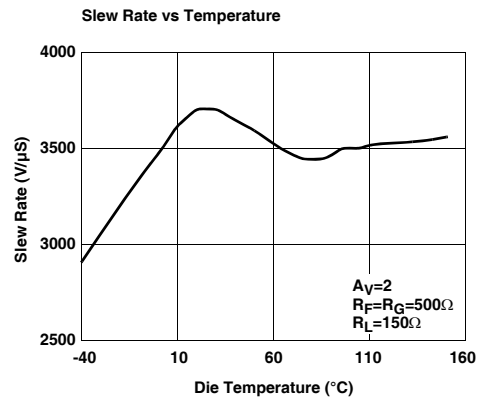
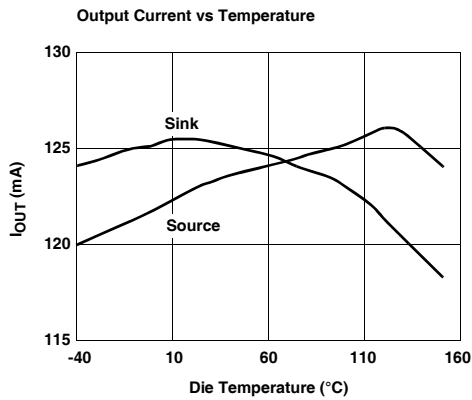
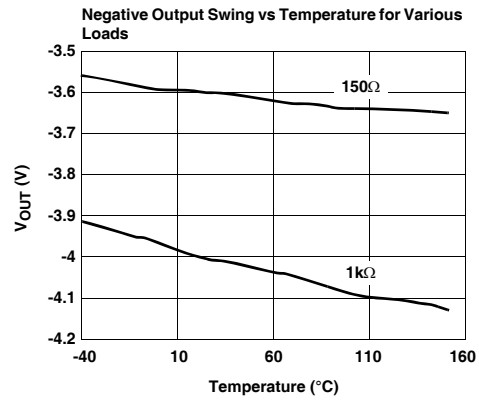
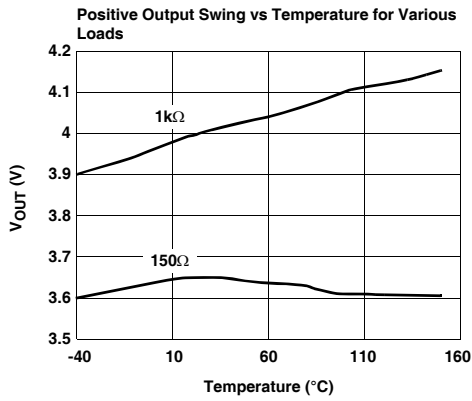
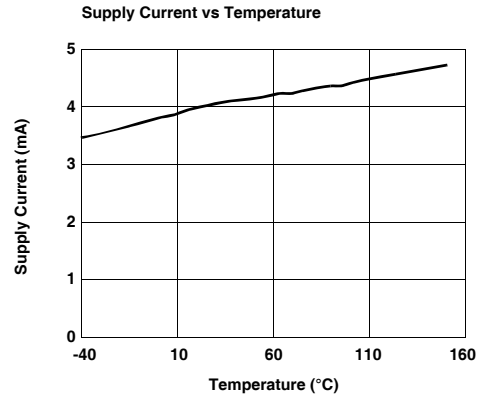
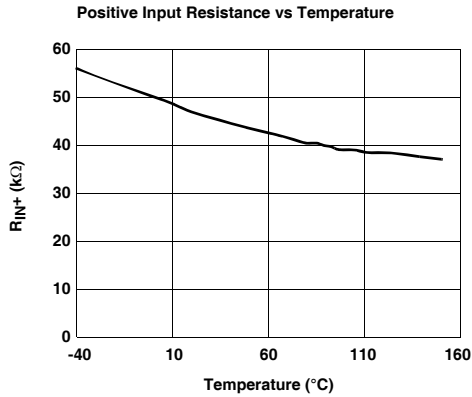
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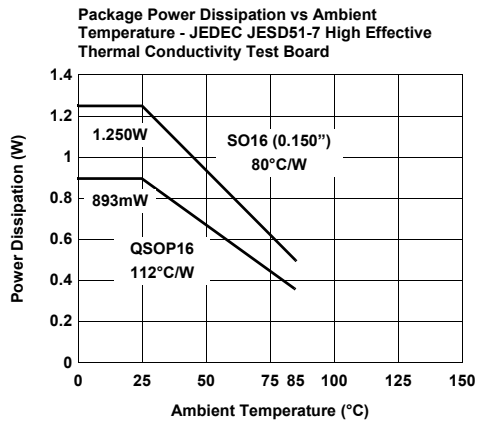
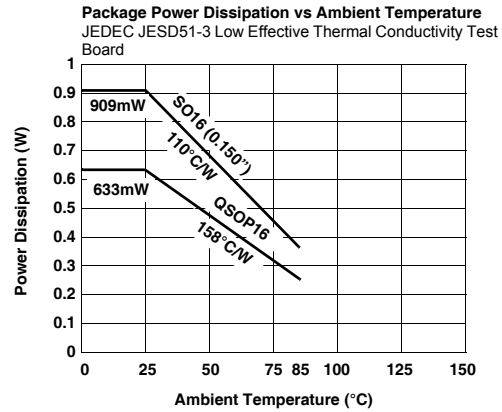
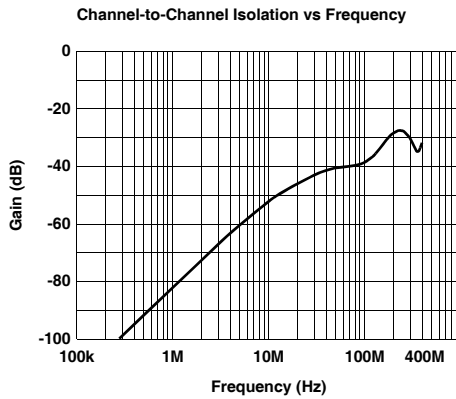
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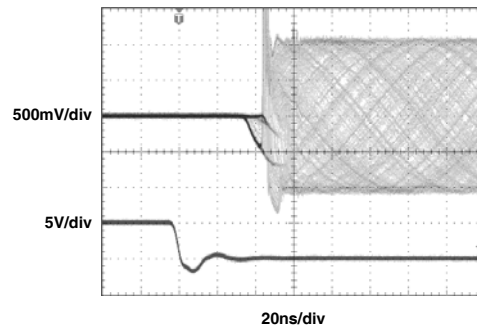
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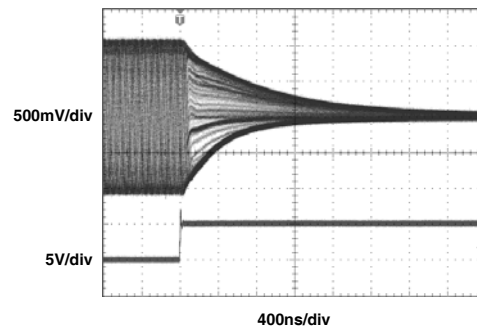
Typical Performance Curves (Continued)



Enable Response



Disable Response



PIN DESCRIPTIONS

16-PIN SO (0.150")	16-PIN QSOP	PIN NAME	FUNCTION	EQUIVALENT CIRCUIT
1	1	INA+	Non-inverting input, channel A	<p>Circuit 1</p>
2	2	$\overline{\text{CEA}}$	Chip enable, channel A	<p>Circuit 2</p>
3	3	VS-	Negative supply	
4	4	$\overline{\text{CEB}}$	Chip enable, channel B	(See circuit 2)
5	5	INB+	Non-inverting input, channel B	(See circuit 1)
6, 11	6, 11	NC	Not connected	
7	7	$\overline{\text{CEC}}$	Chip enable, channel C	(See circuit 2)
8	8	INC+	Non-inverting input, channel C	(See circuit 1)
9	9	INC-	Inverting input, channel C	(See circuit 1)
10	10	OUTC	Output, channel C	<p>Circuit 3</p>
12	12	INB-	Inverting input, channel B	(See circuit 1)
13	13	OUTB	Output, channel B	(See circuit 3)
14	14	VS+	Positive supply	
15	15	OUTA	Output, channel A	(See circuit 3)
16	16	INA-	Inverting input, channel A	(See circuit 1)

Applications Information

Product Description

The EL5393A is a current-feedback operational amplifier that offers a wide -3dB bandwidth of 300MHz and a low supply current of 4mA per amplifier. The EL5393A works with supply voltages ranging from a single 5V to 10V and they are also capable of swinging to within 1V of either supply on the output. Because of their current-feedback topology, the EL5393A does not have the normal gain-bandwidth product associated with voltage-feedback

operational amplifiers. Instead, its -3dB bandwidth to remain relatively constant as closed-loop gain is increased. This combination of high bandwidth and low power, together with aggressive pricing make the EL5393A the ideal choice for many low-power/high-bandwidth applications such as portable, handheld, or battery-powered equipment.

For varying bandwidth needs, consider the EL5191 with 1GHz on a 9mA supply current or the EL5192 with 600MHz on a 6mA supply current. Versions include single, dual, and triple amp packages with 5-pin SOT23, 16-pin QSOP, and 8-pin or 16-pin SO (0.150") outlines.

Power Supply Bypassing and Printed Circuit Board Layout

As with any high frequency device, good printed circuit board layout is necessary for optimum performance. Low impedance ground plane construction is essential. Surface mount components are recommended, but if leaded components are used, lead lengths should be as short as possible. The power supply pins must be well bypassed to reduce the risk of oscillation. The combination of a 4.7 μ F tantalum capacitor in parallel with a 0.01 μ F capacitor has been shown to work well when placed at each supply pin.

For good AC performance, parasitic capacitance should be kept to a minimum, especially at the inverting input. (See the Capacitance at the Inverting Input section) Even when ground plane construction is used, it should be removed from the area near the inverting input to minimize any stray capacitance at that node. Carbon or Metal-Film resistors are acceptable with the Metal-Film resistors giving slightly less peaking and bandwidth because of additional series inductance. Use of sockets, particularly for the SO (0.150") package, should be avoided if possible. Sockets add parasitic inductance and capacitance which will result in additional peaking and overshoot.

Disable/Power-Down

The EL5393A amplifier can be disabled placing its output in a high impedance state. When disabled, the amplifier supply current is reduced to < 450 μ A. The EL5393A is disabled when its $\overline{\text{CE}}$ pin is pulled up to within 1V of the positive supply. Similarly, the amplifier is enabled by floating or pulling its $\overline{\text{CE}}$ pin to at least 3V below the positive supply. For ± 5 V supply, this means that an EL5393A amplifier will be enabled when $\overline{\text{CE}}$ is 2V or less, and disabled when $\overline{\text{CE}}$ is above 4V. Although the logic levels are not standard TTL, this choice of logic voltages allows the EL5393A to be enabled by tying $\overline{\text{CE}}$ to ground, even in 5V single supply applications. The $\overline{\text{CE}}$ pin can be driven from CMOS outputs.

Capacitance at the Inverting Input

Any manufacturer's high-speed voltage- or current-feedback amplifier can be affected by stray capacitance at the inverting input. For inverting gains, this parasitic capacitance has little effect because the inverting input is a virtual ground, but for non-inverting gains, this capacitance (in conjunction with the feedback and gain resistors) creates a pole in the feedback path of the amplifier. This pole, if low enough in frequency, has the same destabilizing effect as a zero in the forward open-loop response. The use of large-value feedback and gain resistors exacerbates the problem by further lowering the pole frequency (increasing the possibility of oscillation).

The EL5393A has been optimized with a 475 Ω feedback resistor. With the high bandwidth of these amplifiers, these resistor values might cause stability problems when combined with parasitic capacitance, thus ground plane is

not recommended around the inverting input pin of the amplifier.

Feedback Resistor Values

The EL5393A has been designed and specified at a gain of +2 with R_F approximately 500 Ω . This value of feedback resistor gives 200MHz of -3dB bandwidth at $A_V=2$ with 2dB of peaking. With $A_V=-2$, an R_F of approximately 500 Ω gives 175MHz of bandwidth with 0.2dB of peaking. Since the EL5393A is a current-feedback amplifier, it is also possible to change the value of R_F to get more bandwidth. As seen in the curve of Frequency Response for Various R_F and R_G , bandwidth and peaking can be easily modified by varying the value of the feedback resistor.

Because the EL5393A is a current-feedback amplifier, its gain-bandwidth product is not a constant for different closed-loop gains. This feature actually allows the EL5393A to maintain about the same -3dB bandwidth. As gain is increased, bandwidth decreases slightly while stability increases. Since the loop stability is improving with higher closed-loop gains, it becomes possible to reduce the value of R_F below the specified 475 Ω and still retain stability, resulting in only a slight loss of bandwidth with increased closed-loop gain.

Supply Voltage Range and Single-Supply Operation

The EL5393A has been designed to operate with supply voltages having a span of greater than 5V and less than 10V. In practical terms, this means that the EL5393A will operate on dual supplies ranging from ± 2.5 V to ± 5 V. With single-supply, the EL5393A will operate from 5V to 10V.

As supply voltages continue to decrease, it becomes necessary to provide input and output voltage ranges that can get as close as possible to the supply voltages. The EL5393A has an input range which extends to within 2V of either supply. So, for example, on +5V supplies, the EL5393A has an input range which spans ± 3 V. The output range of the EL5393A is also quite large, extending to within 1V of the supply rail. On a ± 5 V supply, the output is therefore capable of swinging from -4V to +4V. Single-supply output range is larger because of the increased negative swing due to the external pull-down resistor to ground.

Video Performance

For good video performance, an amplifier is required to maintain the same output impedance and the same frequency response as DC levels are changed at the output. This is especially difficult when driving a standard video load of 150 Ω , because of the change in output current with DC level. Previously, good differential gain could only be achieved by running high idle currents through the output transistors (to reduce variations in output impedance.) These currents were typically comparable to the entire 4mA supply current of each EL5393A amplifier. Special circuitry

has been incorporated in the EL5393A to reduce the variation of output impedance with current output. This results in dG and dP specifications of 0.03% and 0.04°, while driving 150Ω at a gain of 2.

Video performance has also been measured with a 500Ω load at a gain of +1. Under these conditions, the EL5393A has dG and dP specifications of 0.03% and 0.04°.

Output Drive Capability

In spite of its low 4mA of supply current, the EL5393A is capable of providing a minimum of ±95mA of output current. With a minimum of ±95mA of output drive, the EL5393A is capable of driving 50Ω loads to both rails, making it an excellent choice for driving isolation transformers in telecommunications applications.

Driving Cables and Capacitive Loads

When used as a cable driver, double termination is always recommended for reflection-free performance. For those applications, the back-termination series resistor will decouple the EL5393A from the cable and allow extensive capacitive drive. However, other applications may have high capacitive loads without a back-termination resistor. In these applications, a small series resistor (usually between 5Ω and 50Ω) can be placed in series with the output to eliminate most peaking. The gain resistor (R_G) can then be chosen to make up for any gain loss which may be created by this additional resistor at the output. In many cases it is also possible to simply increase the value of the feedback resistor (R_F) to reduce the peaking.

Current Limiting

The EL5393A has no internal current-limiting circuitry. If the output is shorted, it is possible to exceed the Absolute Maximum Rating for output current or power dissipation, potentially resulting in the destruction of the device.

Power Dissipation

With the high output drive capability of the EL5393A, it is possible to exceed the 125°C Absolute Maximum junction temperature under certain very high load current conditions. Generally speaking when R_L falls below about 25Ω, it is important to calculate the maximum junction temperature (T_{JMAX}) for the application to determine if power supply voltages, load conditions, or package type need to be modified for the EL5393A to remain in the safe operating area. These parameters are calculated as follows:

$$T_{JMAX} = T_{MAX} + (\theta_{JA} \times n \times PD_{MAX})$$

where:

T_{MAX} = Maximum ambient temperature

θ_{JA} = Thermal resistance of the package

n = Number of amplifiers in the package

PD_{MAX} = Maximum power dissipation of each amplifier in the package

PD_{MAX} for each amplifier can be calculated as follows:

$$PD_{MAX} = (2 \times V_S \times I_{SMAX}) + \left[(V_S - V_{OUTMAX}) \times \frac{V_{OUTMAX}}{R_L} \right]$$

where:

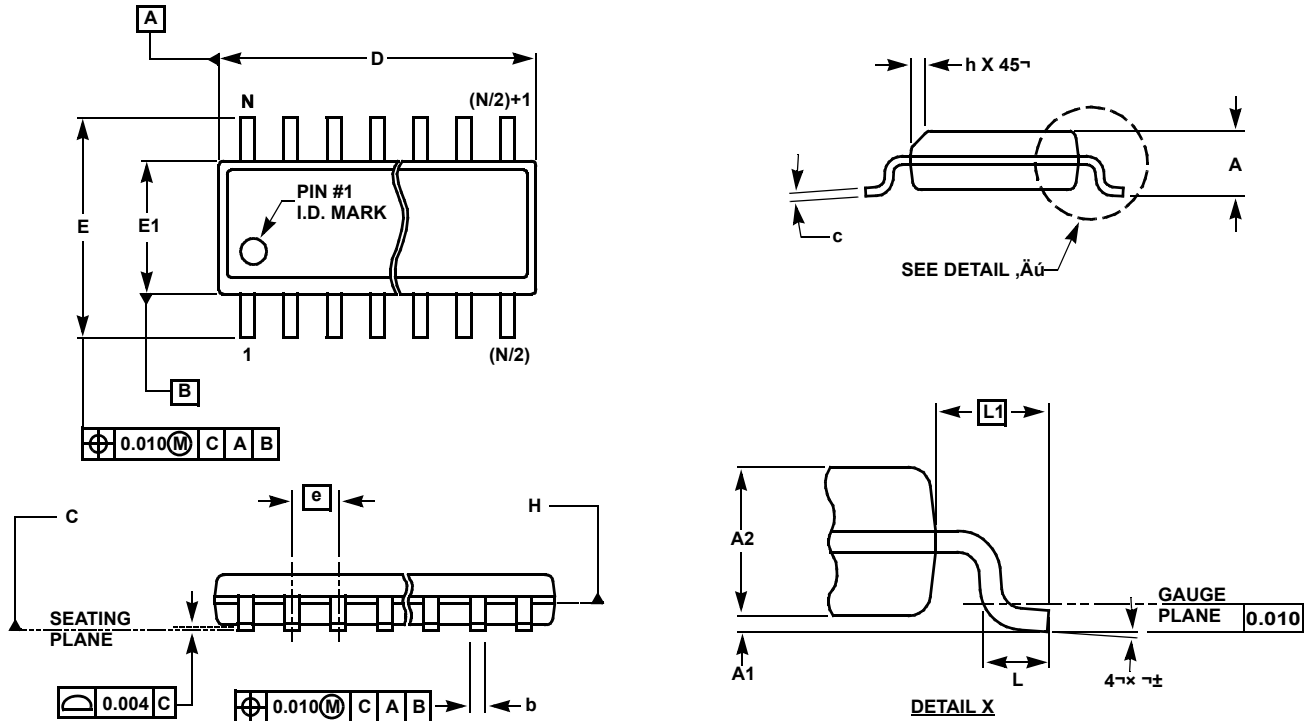
V_S = Supply voltage

I_{SMAX} = Maximum supply current of 1A

V_{OUTMAX} = Maximum output voltage (required)

R_L = Load resistance

Small Outline Package Family (SO)



MDP0027

SMALL OUTLINE PACKAGE FAMILY (SO)

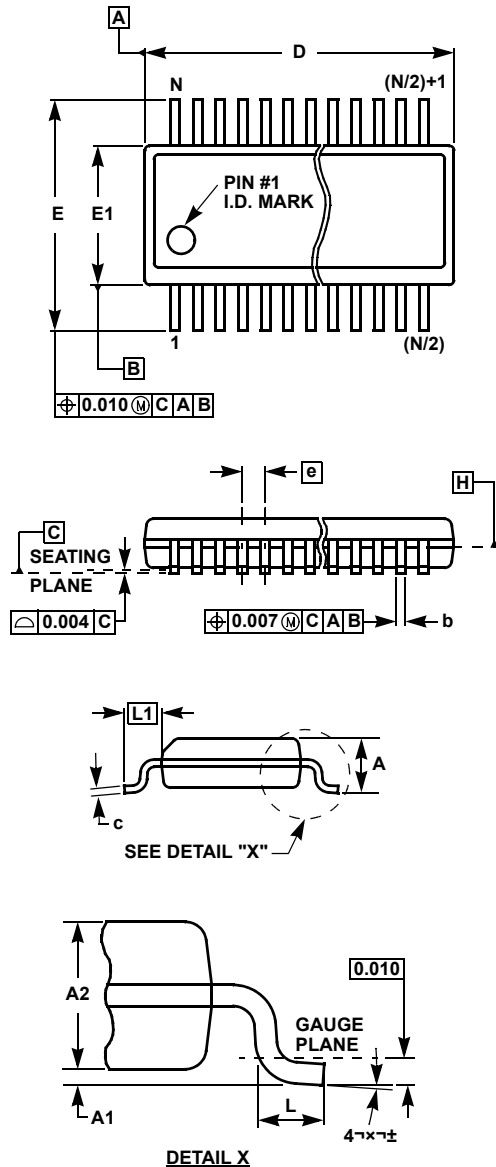
SYMBOL	INCHES							TOLERANCE	NOTES
	SO-8	SO-14	SO16 (0.150")	SO16 (0.300") (SOL-16)	SO20 (SOL-20)	SO24 (SOL-24)	SO28 (SOL-28)		
A	0.068	0.068	0.068	0.104	0.104	0.104	0.104	MAX	-
A1	0.006	0.006	0.006	0.007	0.007	0.007	0.007	±0.003	-
A2	0.057	0.057	0.057	0.092	0.092	0.092	0.092	±0.002	-
b	0.017	0.017	0.017	0.017	0.017	0.017	0.017	±0.003	-
c	0.009	0.009	0.009	0.011	0.011	0.011	0.011	±0.001	-
D	0.193	0.341	0.390	0.406	0.504	0.606	0.704	±0.004	1, 3
E	0.236	0.236	0.236	0.406	0.406	0.406	0.406	±0.008	-
E1	0.154	0.154	0.154	0.295	0.295	0.295	0.295	±0.004	2, 3
e	0.050	0.050	0.050	0.050	0.050	0.050	0.050	Basic	-
L	0.025	0.025	0.025	0.030	0.030	0.030	0.030	±0.009	-
L1	0.041	0.041	0.041	0.056	0.056	0.056	0.056	Basic	-
h	0.013	0.013	0.013	0.020	0.020	0.020	0.020	Reference	-
N	8	14	16	16	20	24	28	Reference	-

Rev. M 2/07

NOTES:

1. Plastic or metal protrusions of 0.006" maximum per side are not included.
2. Plastic interlead protrusions of 0.010" maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994

Quarter Size Outline Plastic Packages Family (QSOP)



MDP0040

QUARTER SIZE OUTLINE PLASTIC PACKAGES FAMILY

SYMBOL	INCHES			TOLERANCE	NOTES
	QSOP16	QSOP24	QSOP28		
A	0.068	0.068	0.068	Max.	-
A1	0.006	0.006	0.006	± 0.002	-
A2	0.056	0.056	0.056	± 0.004	-
b	0.010	0.010	0.010	± 0.002	-
c	0.008	0.008	0.008	± 0.001	-
D	0.193	0.341	0.390	± 0.004	1, 3
E	0.236	0.236	0.236	± 0.008	-
E1	0.154	0.154	0.154	± 0.004	2, 3
e	0.025	0.025	0.025	Basic	-
L	0.025	0.025	0.025	± 0.009	-
L1	0.041	0.041	0.041	Basic	-
N	16	24	28	Reference	-

Rev. F 2/07

NOTES:

1. Plastic or metal protrusions of 0.006" maximum per side are not included.
2. Plastic interlead protrusions of 0.010" maximum per side are not included.
3. Dimensions "D" and "E1" are measured at Datum Plane "H".
4. Dimensioning and tolerancing per ASME Y14.5M-1994.

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